

A Product Line of **Diodes Incorporated** 

**Description** 

1.65V to 5.5V.

processor general purpose I/Os.

disruption during switching.

PERICOM" PI5A4157

### Low Voltage SPDT 0.80 Analog Switch

The PI5A4157 is a high-bandwidth, fast single-pole

double-throw (SPDT) CMOS switch. It can be used as

an analog switch or as a low-delay bus switch. The

device features ultra low RON of  $0.8\Omega$  typical at 3.0V

VCC and will operate over the wide VCC range of

The PI5A4157 features very low quiescent current even

when the control voltage is lower than the VCC supply.

This feature services the mobile handset applications

very well by allowing direct interface with baseband

Break-before-make switching prevents both switches

being enabled simultaneously. This eliminates signal

The control input, S, is independent of supply voltage.

### **Features**

- CMOS Technology for Bus and Analog • Applications
- Low On-Resistance:  $0.8\Omega$  at 3.0V•
- Wide V<sub>CC</sub> Range: 1.65V to 5.5V •
- Rail-to-Rail Signal Range •
- Control Input Overvoltage Tolerance: 5.5V(Min) •
- Fast Transition Speed: 12ns at 5.0V •
- High Bandwidth: 150 MHz .
- **Extended Industrial Temperature Range:** • -40 °C to 85 °C
- Packaging (Pb-free & Green): .
  - -6-pin SOT23
  - -6-pin SC70
  - -6-Pin UDFN 1mm×1mm

### **Applications**

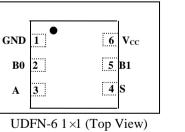
- Cell Phones •
- **PDAs**
- Portable Instrumentation •
- Battery powered Communications •
- **Computer Peripherals**

# **Pin Assignment**

#### 6 S B1 Vcc GND 6 1 2 5 VCC 5 B1 GND 2 **B**0 4 S 3 A B 0 UDFN-6 1×1 (Top View) SOT23-6 and SC70-6(Top View)

### **Pin Description**

Pin No		Pin		
SOT23-6 SC70-6	UDFN-6 1×1	Name	Description	
1	5	B1	Data Port	
2	1	GND	Ground	
3	2	B0	Data Port (Normally connected)	
4	3	А	Common Output/Data Port	
5	6	V <sub>CC</sub>	Positive Power Supply	
6	4	S	Logic control	



### **Logic Function Table**

Logic Inputs(S)	Function
0	$B_0$ connect to A
1	B <sub>1</sub> connect to A

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# **Maximum Ratings**

Storage Temperature	65°C to +150°C
Ambient Temperature with Power Applied	40°C to +85°C
Supply Voltage V <sub>CC</sub>	
DC Switch Voltage V <sub>S</sub>	0.5V to V <sub>CC</sub> +0.5V
DC Input Voltage V <sub>IN</sub>	0.5V to +7.0V
DC Output Current V <sub>OUT</sub>	128mA
DC V <sub>CC</sub> or Ground Current $I_{CC} / I_{GND} \dots$	±100mA
Junction Temperature under Bias (TJ)	150 °C
Junction Lead Temperature (TL)	
(Soldering, 10 seconds)	
ESD (HBM)	5KV
Power Dissipation (PD) @ +85 °C	SOT23 250mW
	SC70 200mW
	UDFN1x1 150mW

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### **Recommended Operating Conditions**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V <sub>CC</sub>	Operating Voltage	-	1.65	-	5.5	V
$V_{IN}$	Control Input Voltage	-	0	-	V <sub>CC</sub>	V
Vs	Switch Input Voltage	-	0	-	V <sub>CC</sub>	V
V <sub>OUT</sub>	Output Voltage	-	0	-	V <sub>CC</sub>	V
$T_A$	Operating Temperature	-	-40	25	85	${}^{\mathbb{C}}$
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time	Control Input $V_{CC} = 2.7V$ to $3.6V$	0	-	10	ns/V
		Control Input $V_{CC} = 4.5V$ to $5.5V$	0	-	5	ns/V

Note: Control input must be held HIGH or LOW; it must not float.

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# **DC Electrical Characteristics**

 $(T_A = -40$  °C to 85 °C, unless otherwise noted.)

Parameter	Description	Test Conditions	Supply Voltage	Min	Тур	Max	Units	
V <sub>IAR</sub>	Analog Input Signal Range	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V	
		$I_O = 100 \text{mA}, V_{IN} = 0 \text{V}$		-	0.7	1.1		
		$I_0 = 100 \text{mA}, V_{IN} = 2.4 \text{V}$	4.5V	-	0.6	1.0		
		$I_{O} = 100 \text{mA}, V_{IN} = 4.5 \text{V}$		-	0.8	1.2		
		$I_O = 100 \text{mA}, V_{IN} = 0 \text{V}$	3.0V	-	0.8	1.3	Ω	
R <sub>ON</sub>	ON Resistance <sup>(1)</sup>	$I_{O} = 100 \text{mA}, V_{IN} = 3.0 \text{V}$	5.0 V	-	0.9	1.9		
		$I_O = 100 \text{mA}, V_{IN} = 0 \text{V}$	2.3V	-	1.0	1.5		
		$I_0 = 100 \text{mA}, V_{IN} = 2.3 \text{V}$	2.3 V	-	1.2	1.8		
	-	$I_O = 100 \text{mA}, V_{IN} = 0 \text{V}$	1.65V	-	1.3	1.9		
	-	$I_0 = 100 \text{mA}, V_{IN} = 1.65 \text{V}$	- 1.65V	-	2.0	2.8		
		$I_A = 100 \text{mA}, V_{Bn} = 3.15 \text{V}$	4.5V	-	0.01	0.03		
۸D	ON Resistance Match	$I_A = 100 \text{mA}, V_{Bn} = 2.1 \text{V}$	3.0V	-	0.02	0.04		
$\Delta R_{ON}$	Between Channels <sup>(1,2,3)</sup>	$I_A = 100 \text{mA}, V_{Bn} = 1.6 \text{V}$	2.3V	-	0.03	0.06	Ω	
		$I_A = 100 \text{mA}, V_{Bn} = 1.15 \text{V}$	1.65V	-	0.03	0.06		
R <sub>ONF</sub>	ON Resistance Flatness <sup>(1,2,4)</sup>	$I_A = 100 \text{mA}, V_{Bn} = 0V, 2.4V, 4.5V$	4.5V	-	0.2	0.4		
		$I_A = 100 \text{mA}, V_{Bn} = 0V, 1.5V, 3.3V$	3.3V	-	0.2	0.4		
		$I_A = 100 \text{mA}, V_{Bn} = 0V, 1.1V, 2.5V$	2.5V	-	0.4	0.6	Ω	
		$I_A = 100 \text{mA}, V_{Bn} = 0 \text{V}, 0.7 \text{V}, 1.8 \text{V}$	1.8V	-	1.0	1.4		
				$V_{CC} = 1.65 V$	0.9	-	-	
			$V_{CC} = 2.3 V$	1.0	-	-	V	
$V_{IH}$	Input High Voltage	Logic High Level	$V_{CC} = 3V$	1.1	-	-		
			$V_{CC} = 4.2V$	1.2	-	-	_	
			$V_{\rm CC} = 5.5 V$	1.3	-	-		
			$V_{CC} = 1.65V$	-	-	0.6	_	
V	Input Low Voltage	Logic Low Level	$V_{CC} = 2.3V$	-	-	0.6	v	
V <sub>IL</sub>	niput Low voltage	Logic Low Level	$\frac{V_{CC} = 3V}{V_{CC} = 4.2V}$	-	-	0.8	- V	
			$V_{CC} = 4.2 V$ $V_{CC} = 5.5 V$	-	_	0.8	-	
$I_{OFF(NO)}$ or $I_{OFF(NC)}$	Source Off Leakage Current	V <sub>CC</sub> =5.5V, VA =1V, 4.5V VBn =1V, 4.5V	$V_{\rm CC} = 3V$	-20	-	+20		
$I_{NC(ON)},$ $I_{NO(ON)},$ $I_{COM (ON)}$	Channel On Leakage Current	-	$V_{CC} = 1.65$ to $5.5V$	-40	-	+40	nA	
	Quiescent Supply	All channels ON or OFF,	$V_{CC} = 3.6V$	-	0.002	0.1		
I <sub>CC</sub>	Current	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$	$V_{\rm CC} = 5.5 V$	-	0.002	0.1	- μΑ	
I <sub>CCT</sub>	Increase in I <sub>CC</sub> per Input	Input at 2.7V	$V_{\rm CC} = 4.3 V$	-	0.2	10.0	μΑ	

Notes:

1. Measured by voltage drop between A and B pins at the indicated current through the device. ON resistance is determined by the lower of the voltages on two ports (A or B).

2. Parameter is characterized but not tested in production.

3.  $\Delta R_{ON} = R_{ON} \text{ max} - R_{ON} \text{ min.}$  measured at identical V<sub>CC</sub>, temperature and voltage levels.

4. Flatness is defined as difference between maximum and minimum value of ON resistance over the specified range of conditions.

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# Capacitance (1)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
C <sub>IN</sub>	Control Input		-	3.5	-	
C <sub>IO-B</sub>	For B Port, Switch OFF	$V_{CC} = 5.0V, f = 1$ MHz, $T_A=25$ °C	-	15.0	-	рF
C <sub>IOA-ON</sub>	For A Port, Switch ON		-	34.0	-	r -

Notes:

1. Capacitance is characterized but not tested in production

# Switch and AC Characteristics (1)

Parameter	Description	Test Conditions	Supply Voltage	Min	Тур	Max	Units
t	Break Before	See Figure 2	$V_{\rm CC} = 2.7  \text{V}$ to 3.6 V	-	10	20	
t <sub>BBM</sub>	Make Time	See Figure 2	$V_{\rm CC} = 4.5 \text{V}$ to $5.5 \text{V}$	-	6	12	
t	Turn on Time		$V_{\rm CC} = 2.7  \text{V}$ to $3.6  \text{V}$	-	12	25	
t <sub>on</sub>	Turn on Time	See Figure 1	$V_{\rm CC} = 4.5 V$ to 5.5 V	-	9	18	ns
t	Turn off Time	See Figure 1	$V_{\rm CC} = 2.7  \text{V}$ to 3.6 V	-	17	35	
t <sub>off</sub>	Turn off Time	See Figure 1	$V_{\rm CC} = 4.5 V$ to 5.5 V	-	10	20	
0	Q Charge Injection	$C_L = 1nF, V_{GEN} = 0V,$ $R_{GEN} = 0\Omega.$ See Figure 3	$V_{\rm CC} = 5.0 V$	-	35	-	pC
Q			$V_{CC} = 3.3 V$	-	25	-	pe
OIRR	Off Isolation	$\begin{split} & \textbf{R}_{L} = 50\Omega,  \textbf{V}_{GEN} = 0\textbf{V}, \\ & \textbf{R}_{GEN} = 0\Omega,  \textbf{f} = 1\textbf{MHz}. \\ & \textbf{See Figure 4}^{(2)} \end{split}$	$V_{\rm CC}$ =1.65V to 5.5V	-	-70	_	dB
X <sub>TALK</sub>	Crosstalk Isolation	f=1MHz, See Figure 5	$V_{CC} = 1.65 V$ to 5.5V	-	-70	-	
f3dB	-3dB Bandwidth	See Figure 8	$V_{\rm CC} = 1.65  \text{V}$ to 5.5 V	-	150	-	MHz
T <sub>HD</sub>	Total Harmonic Distortion	$R_L$ =600Ω, $V_{IN}$ =0.5Vpp, f=20Hz to 20kHz See Figure 9	$V_{\rm CC} = 2.7 V$ to $4.2 V$	-	0.015	-	%

Notes:

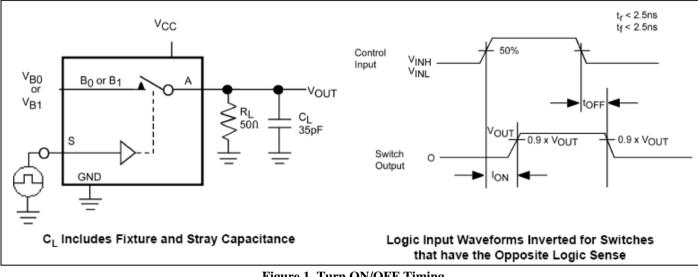
1. Guaranteed by design.

2. Off Isolation = 20 Log<sub>10</sub> [  $V_{Bn}/V_A$  ] and is measured in dB.





# **Test Circuits and Timing Diagrams**





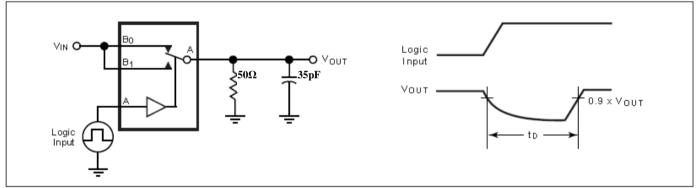
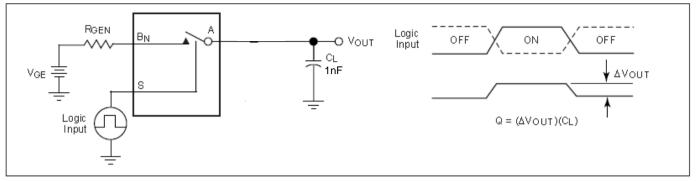


Figure 2. Break Before Make Interval Timing

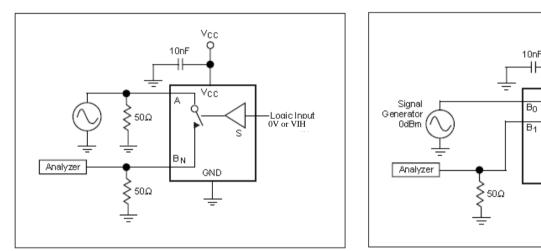
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**Figure 3. Charge Injection Test** 



**Figure 4. Off Isolation** 

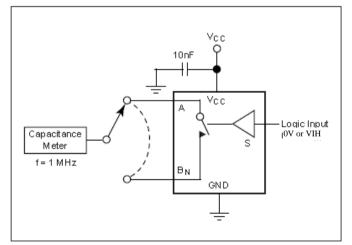


Figure 6. Channel Off Capacitance

**Figure 5. Crosstalk** 

Vcc

Vcc

GND

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<u>ξ</u>50Ω

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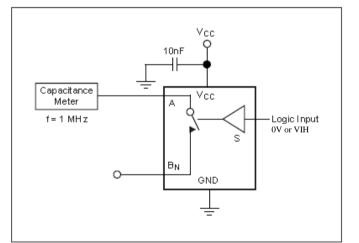
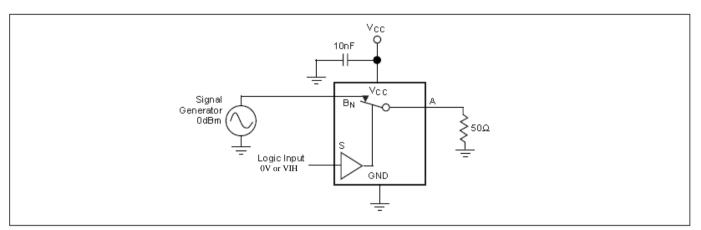


Figure 7. Channel On Capacitance

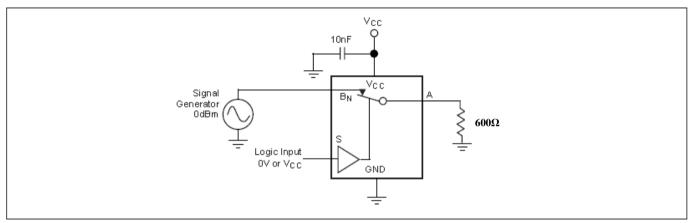
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#### Figure 8. Bandwidth



**Figure 9. Harmonic Distortion** 

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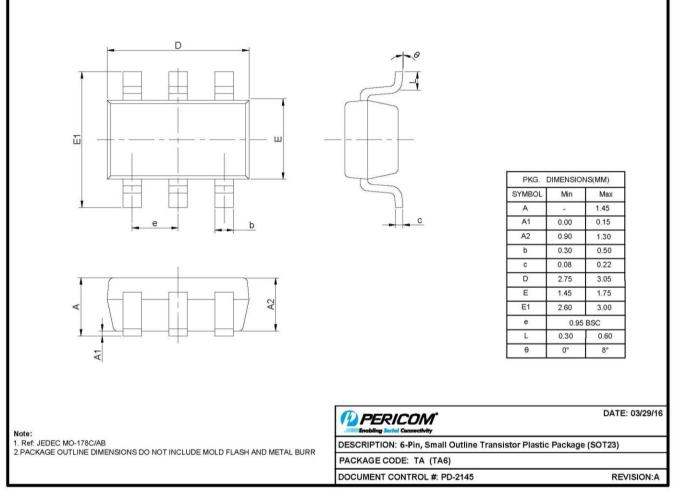


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### **Mechanical Information**

TA (6-pin SOT23)

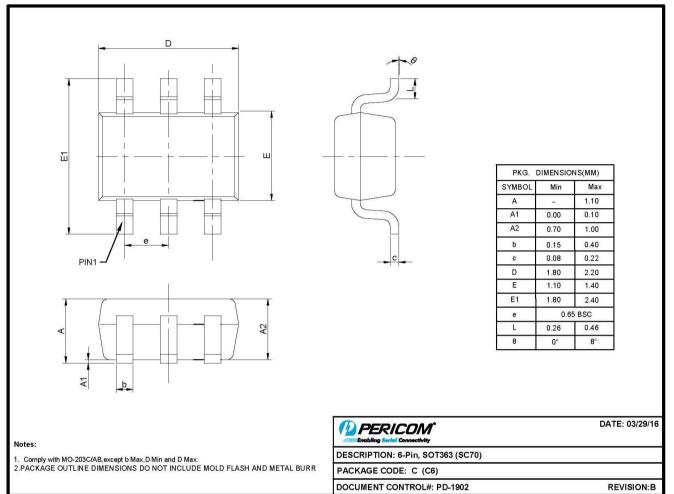


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#### C (6-pin SC70)

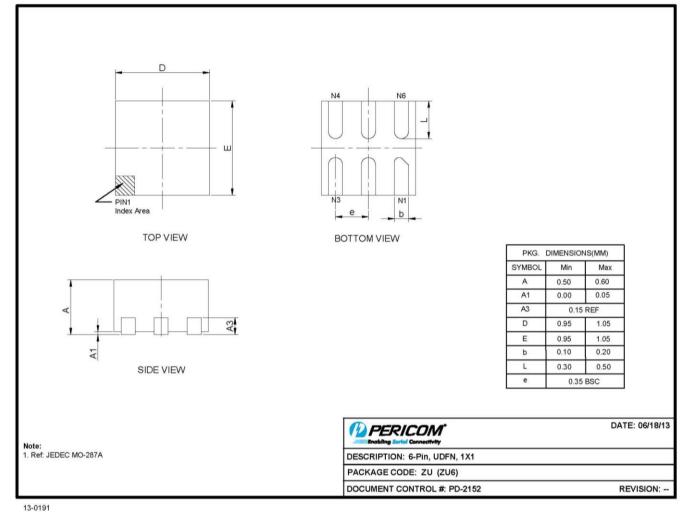


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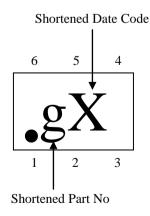




#### ZU (6-pin UDFN 1x1)



### **Marking Description**







Note: For latest package info, please check: http://www.pericom.com/products/packaging/mechanicals.php

# **Ordering Information**

Part Number	Package Code	Package	Top Marking
PI5A4157CEX	С	6-Pin, SOT363 (SC70), Tape & Reel	mA
PI5A4157TAEX	ТА	6-Pin, Small Outline Transistor Plastic Package (SOT23), Tape & reel	mA
PI5A4157ZUEX	ZU	6-Pin, 1x1 (UDFN), Tape & reel	g

#### Notes:

• Thermal characteristics can be found on the company web site at www.pericom.com/packaging/

• E = Pb-free and Green

• X suffix = Tape/Reel

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PI5A4157

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